

Vishay Semiconductors

Schottky Rectifier, 2 x 20 A



PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 20 A				
V _R	45 V				
V _F at I _F	0.48 V				
I _{RM} max.	115 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Common cathode				
E _{AS}	20 mJ				

FEATURES

- 150 °C T_J operation
- · Very low forward voltage drop
- · High frequency operation



- High purity, high temperature epoxy encapsulation for enhanced mechanical strength RoHS COMPLIANT and moisture resistance
- HALOGEN • Guard ring for enhanced ruggedness and long FREE term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	40	A			
V _{RRM}		45	V			
I _{FSM}	t _p = 5 μs sine	1240	A			
V _F	20 A_{pk} , T_J = 125 °C (per leg)	0.48	V			
TJ	Range	- 55 to 150	٦°			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-40CTQ045PbF	VS-40CTQ045-N3	UNITS		
Maximum DC reverse voltage	V _R	45	45	V		
Maximum working peak reverse voltage	V _{RWM}	45	43	v		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS		
Maximum average forward current per leg		$I_{F(AV)}$ 50 % duty cycle at T _C = 116 °C, rectangular waveform -		20			
See fig. 5 per device	IF(AV)			40			
Maximum peak one cycle non-repetitive surge current per leg	I	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1240	A		
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	350			
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 3 A, L = 4.4 mH		20	mJ		
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to ze Frequency limited by T _J maxim		3	А		

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS			
		20 A	T.I = 25 °C	0.53	v			
Maximum forward voltage drop per leg See fig. 1	V _{FM} ⁽¹⁾	40 A	1j=25 0	0.68				
	VFM ("	20 A	T - 105 °C	0.48				
		40 A	T _J = 125 °C	0.67				
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	3	mA			
See fig. 2	IRM (')	T _J = 125 °C	VR = naleu VR	115				
Threshold voltage	V _{F(TO)}	T T maximum		0.27	V			
Forward slope resistance	r _t	ij = ij maximum	$T_J = T_J$ maximum		mΩ			
Maximum junction capacitance per leg	CT	V_{R} = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 $^{\circ}\mathrm{C}$		2800	pF			
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs			

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHAN	THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storag temperature range	9	T _J , T _{Stg}		- 55 to 150	°C		
Maximum thermal resistance, junction to case per leg		D	D. DO sucritica				
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation	1.0	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50			
Approvimeto weight				2	g		
Approximate weight				0.07	oz.		
Manualian tanan	minimum			6 (5)	kgf ⋅ cm		
Mounting torque	maximum	1		12 (10)	(lbf ⋅ in)		
Marking device			Case style TO-220AB	40CTQ045			

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Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)



Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mbox{Pd} = \mbox{Forward power loss} = \mbox{I}_{F(AV)} \ x \ V_{FM} \ at \ (\mbox{I}_{F(AV)}/D) \ (see \ fig. \ 6); \\ \mbox{Pd}_{REV} = \ \mbox{Inverse power loss} = \ V_{R1} \ x \ \mbox{I}_{R} \ (1 - D); \ \mbox{I}_{R} \ at \ V_{R1} = \ 10 \ V \\ \end{array}$

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ORDERING INFORMATION TABLE

Device code	VS-	40	с	т	Q	045	PbF			
		(2)	(3)	(4)	(5)	6	(7)			
	1 · · 2 · · 3 · ·	Vishay Semiconductors product Current rating (40 = 40 A) Circuit configuration: C = Common cathode Package: T = TO-220								
	5 - 6 -	· Volt	Schottky "Q" series Voltage rating (045 = 45 V)							
	7 -	• F	bF = Le	ntal digit ad (Pb)	-free an					

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-40CTQ045PbF	50	1000	Antistatic plastic tube			
VS-40CTQ045-N3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions		www.vishay.com/doc?95222		
Part marking information	TO-220AB PbF	www.vishay.com/doc?95225		
	TO-220AB -N3	www.vishay.com/doc?95028		



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TO-220AB

DIMENSIONS in millimeters and inches





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<u>Diodes</u> 1. - Anode/open 2. - Cathode

2.	-	Cathode
3.	-	Anode

SYMBOL	MILLIM	IETERS	INC	NOTES	Γ	
	MIN.	MAX.	MIN.	MAX.	NOTES	
A	4.25	4.65	0.167	0.183		
A1	1.14	1.40	0.045	0.055		
A2	2.56	2.92	0.101	0.115]
b	0.69	1.01	0.027	0.040		1
b1	0.38	0.97	0.015	0.038	4	
b2	1.20	1.73	0.047	0.068		
b3	1.14	1.73	0.045	0.068	4]
С	0.36	0.61	0.014	0.024		
c1	0.36	0.56	0.014	0.022	4	
D	14.85	15.25	0.585	0.600	3	
D1	8.38	9.02	0.330	0.355		
D2	11.68	12.88	0.460	0.507	6	

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- ⁽³⁾ Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimensions: inches
- $^{\rm (6)}$ Thermal pad contour optional within dimensions E, H1, D2 and E1

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 0.414 10.11 10.51 0.398 Е 3,6 E1 6.86 8.89 0.270 0.350 6 E2 0.76 0.030 7 --2.41 2.67 0.095 0.105 е 0.208 e1 4.88 5.28 0.192 H1 6.09 6.48 0.240 0.255 6,7 13.52 14.02 0.532 0.552 Т 3.32 3.82 0.131 0.150 2 L1 ØΡ 3.54 3.73 0.139 0.147 0.102 Q 2.60 3.00 0.118 90° to 93° 90° to 93° θ

Conforms to JEDEC outline TO-220AB

- $^{(7)}$ Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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